



DMP2070UQ

Product Summary

BV _{DSS}	Rds(on)	I _D T _A = +25°C
	44mΩ @ V _{GS} = -4.5V	-4.6A
-20V	57mΩ @ V _{GS} = -2.5V	-4A
	74mΩ @ V _{GS} = -1.8V	-3.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Load Switch

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

P-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP2070UQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

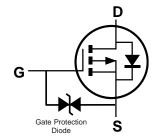
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)

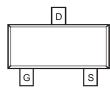




SOT23

Top View





Top View

Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2070UQ-7	SOT23	3,000 / Tape & Reel
DMP2070UQ-13	SOT23	10,000 / Tape & Reel

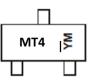
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



MT4 = Product Type Marking Code YM = Date Code Marking \overline{Y} = Year (ex: H = 2020) M = Month (ex: 0 = Sontember)

M = Month (ex: 9 = September)

Date Code Key

,												
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	I	J	К	L	М	N	0	Р	R	S	Т
	1							•				_
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	Vdss	-20	V	
Gate-Source Voltage		V _{GSS}	±8	V
Continuous Drain Current (Note 7) V _{GS} = -4.5V	ID	-4.6 -3.7	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		ldм	-20	A
Maximum Continuous Body Diode Forward Current (Note 6)	ls	-1.9	A	
Avalanche Current, L = 0.1mH (Note 8)	las	-14	A	
Avalanche Energy, L = 0.1mH (Note 8)		Eas	10	mJ

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.83	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	153	°C/W
Total Power Dissipation (Note 6)		PD	1.4	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	90	80 AM
Thermal Resistance, Junction to Case (Note 7)		R _{0JC}	15.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	• • • • • • •		• 76		•		
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	—	V	$V_{GS} = 0V, I_D = -1mA$	
Zero Gate Voltage Drain Current	IDSS			-1	μA	V _{DS} = -20V, V _{GS} = 0V	
Gate-Source Leakage	IGSS	_	_	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)						÷	
Gate Threshold Voltage	Vgs(th)	-0.45	—	-0.95	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
		_	37	44		$V_{GS} = -4.5V, I_D = -2A$	
Static Drain-Source On-Resistance	RDS(ON)	_	48	57	mΩ	Vgs = -2.5V, ID = -2A	
		_	65	74		$V_{GS} = -1.8V, I_D = -2A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.1	V	$V_{GS} = 0V, I_{S} = -2.1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		118	_			
Output Capacitance	Coss	_	79	_	pF	$V_{DS} = -10V$, $V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	11	_			
Gate Resistance	Rg	_	459	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -8V)	Qg	_	8.2	_			
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	17.8	_	nC		
Gate-Source Charge	Qgs	_	1.4	_	nc	$V_{DD} = -10V, I_D = -2A$	
Gate-Drain Charge	Q _{gd}	_	1.2	_			
Turn-On Delay Time	tD(ON)	_	115	_			
Turn-On Rise Time	t _R	_	304	_		$V_{GS} = -4.5V, V_{DD} = -10V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	780	_	ns	$R_G = 1\Omega$, $I_D = -2A$	
Turn-Off Fall Time	tF		666	—]		
Reverse Recovery Time	trr			—	ns	IF = -2A, di/dt = -100A/µs	
Reverse Recovery Charge	QRR	_	—	_	nC	IF = -2A, di/dt = -100A/µs	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad).

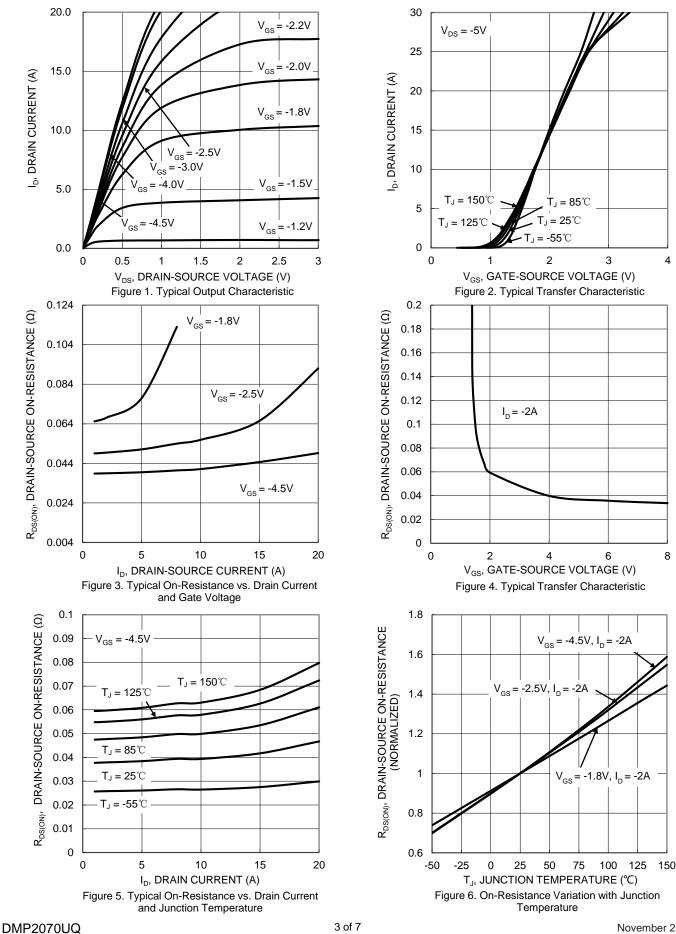
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to product testing.



DMP2070UQ



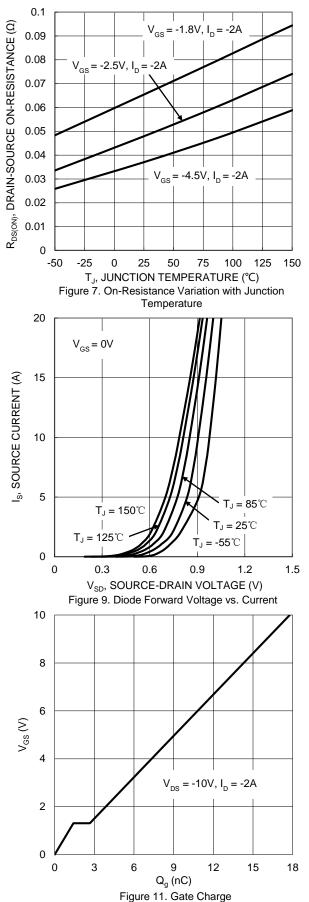
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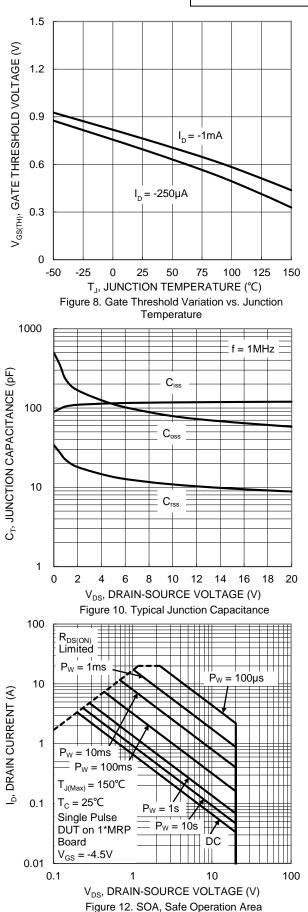
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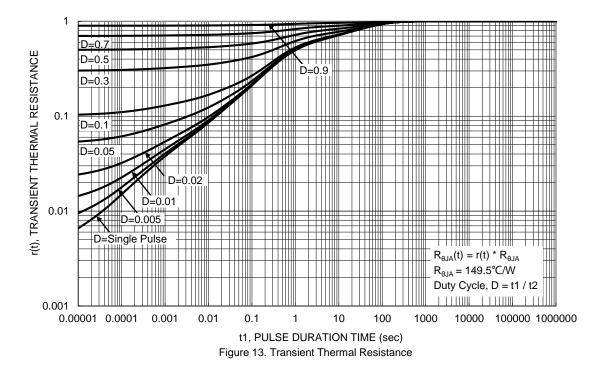
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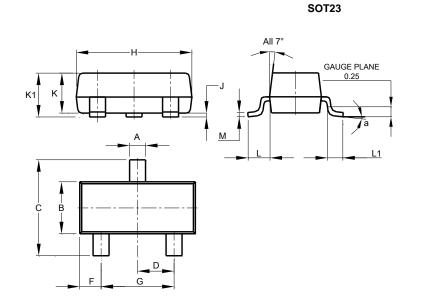






Package Outline Dimensions

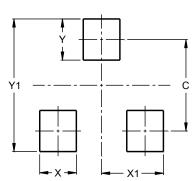
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
в	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
К	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
L	0.45	0.61	0.55			
L1	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

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